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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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#### DATA SHEET



### MOS FIELD EFFECT TRANSISTOR

PACKAGE DRAWING (Unit: mm)

N-channel

P-channel 3

6.0 ±0.3

4.0

0.5 ±0.2

0.6

**EQUIVALENT CIRCUITS** 

 $0.40^{+0.11}_{-0.05}$   $\oplus$  0.12  $\bigcirc$ 

1.27

Source 1

2 : Gate 1 7, 8: Drain 1

: Source 2 : Gate 2

-1.0

□ 0.10

5, 6: Drain 2

# $\mu$ PA2790GR

# SWITCHING N- AND P-CHANNEL POWER MOS FET

#### **DESCRIPTION**

The  $\mu$  PA2790GR is N- and P-channel MOS Field Effect

Transistors designed for Motor Drive application.

#### **FEATURES**

• Low on-state resistance

N-channel R<sub>DS(on)1</sub> = 28 m $\Omega$  MAX. (V<sub>GS</sub> = 10 V, I<sub>D</sub> = 3 A)

 $R_{DS(on)2} = 40 \text{ m}\Omega \text{ MAX.} (V_{GS} = 4.5 \text{ V}, I_D = 3 \text{ A})$ 

P-channel R<sub>DS(on)1</sub> = 60 m $\Omega$  MAX. (V<sub>GS</sub> = -10 V, I<sub>D</sub> = -3 A)

 $R_{DS(on)2} = 80 \text{ m}\Omega \text{ MAX.}$  (Vgs = -4.5 V, ID = -3 A)

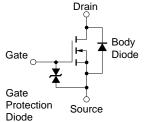
• Low input capacitance

N-channel C<sub>iss</sub> = 500 pF TYP.

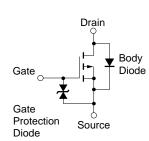
P-channel C<sub>iss</sub> = 460 pF TYP.

- Built-in gate protection diode
- Small and surface mount package (Power SOP8)

#### N-channel



#### P-channel



#### ORDERING INFORMATION

PART NUMBER	PACKAGE
и PA2790GR	Power SOP8

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD.

When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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ARSOLUTE N	MAYIMIIM	RATINGS	$T_{\Lambda} = 25^{\circ}C$	All terminals are	connected )
ADSULUTE		KATINGS (	IA - 25 C.	All tellilliais alt	t connected.)

PARAMETER	SYMBOL	N-CHANNEL	P-CHANNEL	UNIT
Drain to Source Voltage (V <sub>GS</sub> = 0 V)	V <sub>DSS</sub>	30	-30	V
Gate to Source Voltage (VDS = 0 V)	V <sub>GSS</sub>	±20	∓20	V
Drain Current (DC)	I <sub>D(DC)</sub>	±6	∓6	Α
Drain Current (pulse) Note1	I <sub>D(pulse)</sub>	±24	∓24	А
Total Power Dissipation (1 unit) Note2	Рт		W	
Total Power Dissipation (2 units) Note2	Рт	2.0		W
Channel Temperature	Tch	150		°C
Storage Temperature	Tstg	–55 to +150		°C
Single Avalanche Current Note3	las	6	-6	А
Single Avalanche Energy Note3	Eas	3.6	3.6	mJ

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

- 2. Mounted on ceramic substrate of 2000  $\mathrm{mm}^2$  x 1.6  $\mathrm{mm}$
- 3. Starting Tch = 25°C, Vdd =  $\frac{1}{2}$  x Vdss, Rg = 25  $\Omega$ , L = 100  $\mu$ H, Ves = Vess  $\rightarrow$  0 V





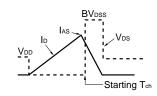
#### **ELECTRICAL CHARACTERISTICS (TA = 25°C. All terminals are connected.)**

#### N-channel

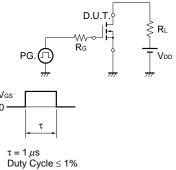
N-Channel						
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V			10	μΑ
Gate Leakage Current	Igss	V <sub>GS</sub> = ±16 V, V <sub>DS</sub> = 0 V			±10	μΑ
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.5		2.5	V
Forward Transfer Admittance Note	y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 3 A	2			S
Drain to Source On-state Resistance Note	RDS(on)1	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 3 A		21	28	mΩ
	RDS(on)2	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 3 A		28	40	mΩ
	RDS(on)3	V <sub>GS</sub> = 4.0 V, I <sub>D</sub> = 3 A		34	53	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V		500		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V		135		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		77		pF
Turn-on Delay Time	t̄d(on)	V <sub>DD</sub> = 15 V, I <sub>D</sub> = 3 A		9.2		ns
Rise Time	tr	V <sub>GS</sub> = 10 V		8.8		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 10 Ω		28		ns
Fall Time	tr	<b>~</b> • • • • • • • • • • • • • • • • • • •		7.4		ns
Total Gate Charge	Q <sub>G</sub>	I <sub>D</sub> = 6 A		12.6		nC
Gate to Source Charge	Qgs	V <sub>DD</sub> = 24 V		1.7		nC
Gate to Drain Charge	Q <sub>GD</sub>	V <sub>GS</sub> = 10 V	_	3.8		nC
Body Diode Forward Voltage Note	V <sub>F(S-D)</sub>	I <sub>F</sub> = 6 A, V <sub>GS</sub> = 0 V		0.85		V
Reverse Recovery Time	trr	I <sub>F</sub> = 6 A, V <sub>GS</sub> = 0 V		18		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		11		nC

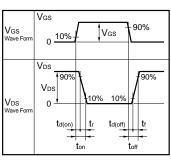
Note Pulsed

#### TEST CIRCUIT 1 AVALANCHE CAPABILITY



#### **TEST CIRCUIT 2 SWITCHING TIME**





#### **TEST CIRCUIT 3 GATE CHARGE**

$$\begin{array}{c|c} D.U.T. \\ \hline I_G = 2 \text{ mA} \\ \hline W. \\ \hline \end{array}$$

$$\begin{array}{c|c} PG. \\ \hline \end{array}$$

$$\begin{array}{c|c} PG. \\ \hline \end{array}$$

$$\begin{array}{c|c} O.U.T. \\ \hline \end{array}$$

$$\begin{array}{c|c} \hline \\ \hline \end{array}$$

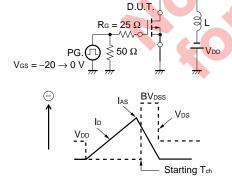
$$\begin{array}{c|c} O.U.T. \\ \hline \end{array}$$

#### P-channel

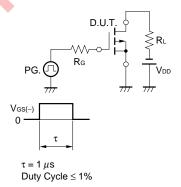
P-Channel						
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = -30 V, V <sub>GS</sub> = 0 V			-10	μΑ
Gate Leakage Current	Igss	V <sub>GS</sub> = ∓16 V, V <sub>DS</sub> = 0 V			∓10	μΑ
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1 mA	-1.0		-2.5	٧
Forward Transfer Admittance Note	y <sub>fs</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -3 A	2			S
Drain to Source On-state Resistance Note	RDS(on)1	V <sub>GS</sub> = -10 V, I <sub>D</sub> = -3 A		43	60	mΩ
	RDS(on)2	$V_{GS} = -4.5 \text{ V}, I_{D} = -3 \text{ A}$		58	80	mΩ
	RDS(on)3	$V_{GS} = -4.0 \text{ V}, I_{D} = -3 \text{ A}$		65	110	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = -10 V		460		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V		130		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		77		pF
Turn-on Delay Time	<b>t</b> d(on)	V <sub>DD</sub> = -15 V, I <sub>D</sub> = -3 A		8.5		ns
Rise Time	<b>t</b> r	V <sub>GS</sub> = -10 V		4.8		ns
Turn-off Delay Time	<b>t</b> d(off)	R <sub>G</sub> = 10 Ω	<	42		ns
Fall Time	t <sub>f</sub>			19		ns
Total Gate Charge	Q <sub>G</sub>	I <sub>D</sub> = -6 A		11		nC
Gate to Source Charge	Qgs	V <sub>DD</sub> = -24 V		1.7		nC
Gate to Drain Charge	Q <sub>GD</sub>	V <sub>GS</sub> = -10 V		3.3		nC
Body Diode Forward Voltage Note	V <sub>F(S-D)</sub>	I <sub>F</sub> = 6 A, V <sub>GS</sub> = 0 V		0.92		V
Reverse Recovery Time	trr	I <sub>F</sub> = 6 A, V <sub>GS</sub> = 0 V		21		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		12		nC

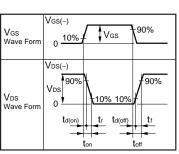
Note Pulsed

### TEST CIRCUIT 1 AVALANCHE CAPABILITY



#### TEST CIRCUIT 2 SWITCHING TIME



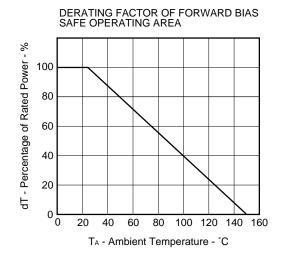


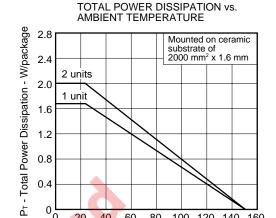
#### **TEST CIRCUIT 3 GATE CHARGE**

$$\begin{array}{c|c} D.U.T. \\ \hline \\ IG = -2 \text{ mA} \\ \hline \\ PG. \\ \hline \\ \end{array}$$

#### TYPICAL CHARACTERISTICS (TA = 25°C)

#### (1) N-channel



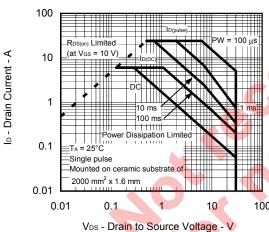


60 80 100 120 140

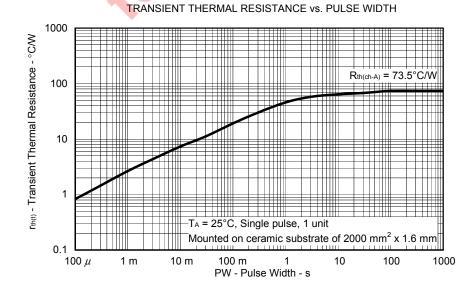
T<sub>A</sub> - Ambient Temperature - °C

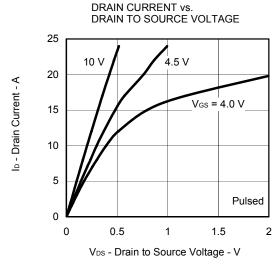
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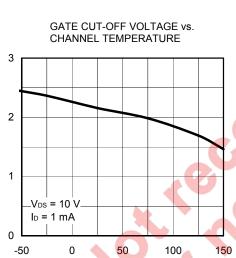
#### FORWARD BIAS SAFE OPERATING AREA



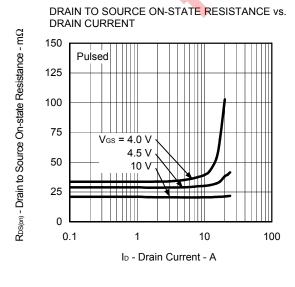


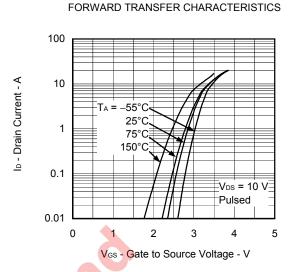


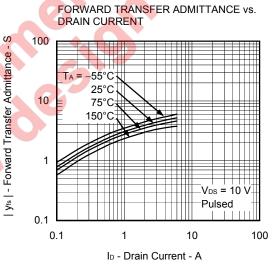


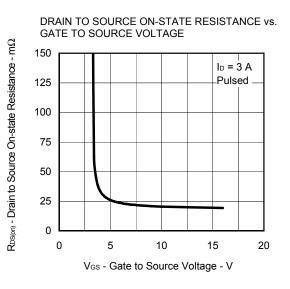


Tch - Channel Temperature - °C

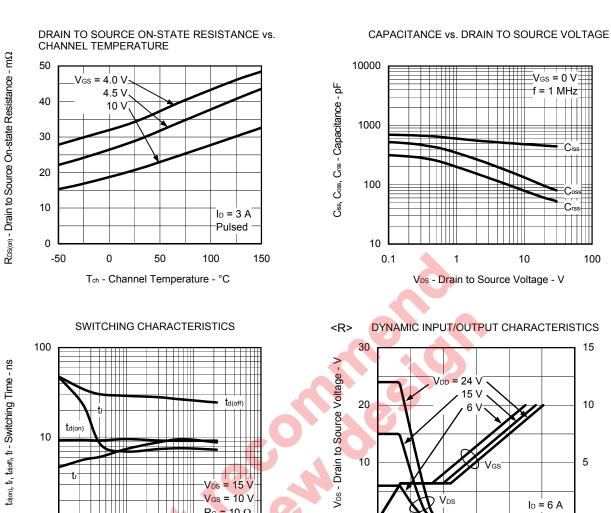


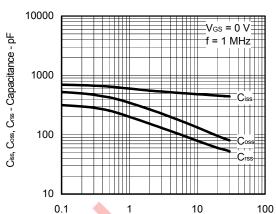




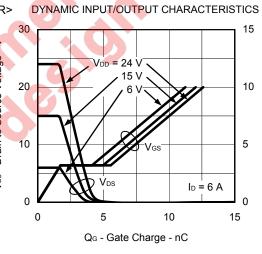


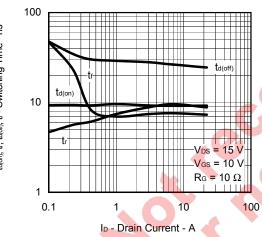
VGS(off) - Gate Cut-off Voltage - V

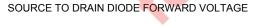


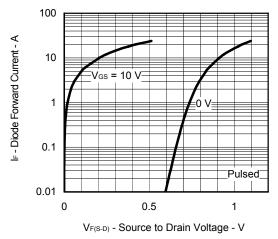


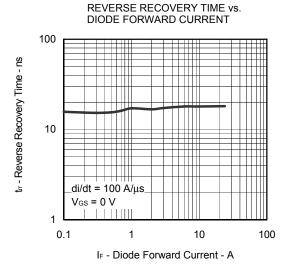
V<sub>DS</sub> - Drain to Source Voltage - V



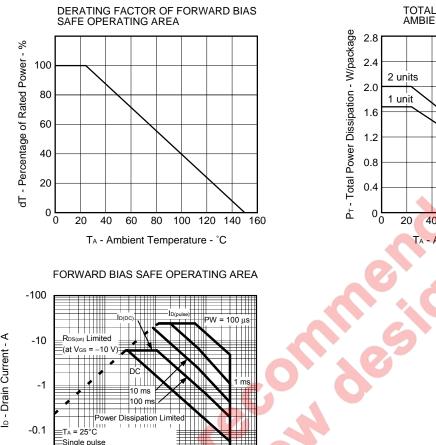




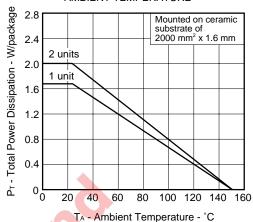




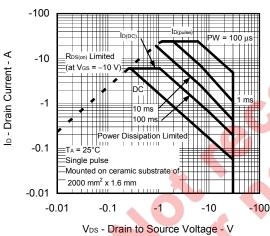
#### (2) P-channel



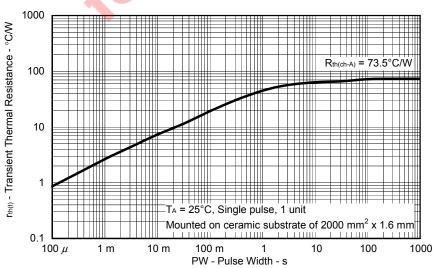
# TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE

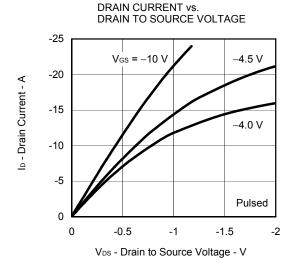


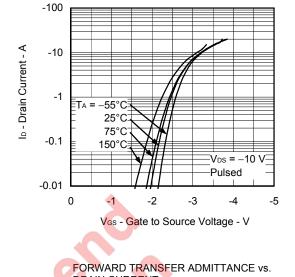
#### FORWARD BIAS SAFE OPERATING AREA



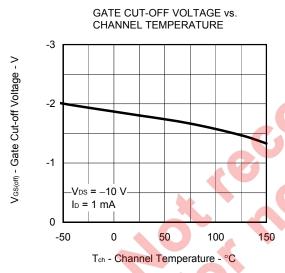


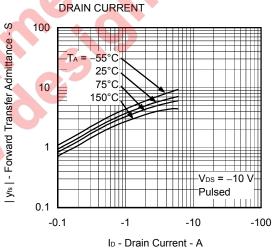


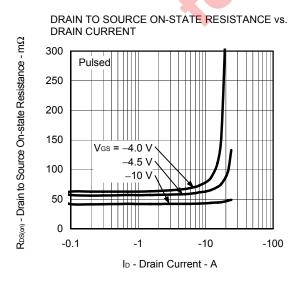


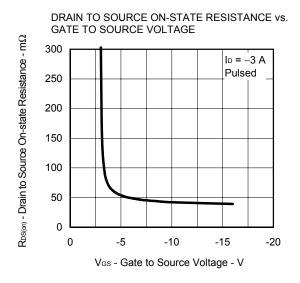


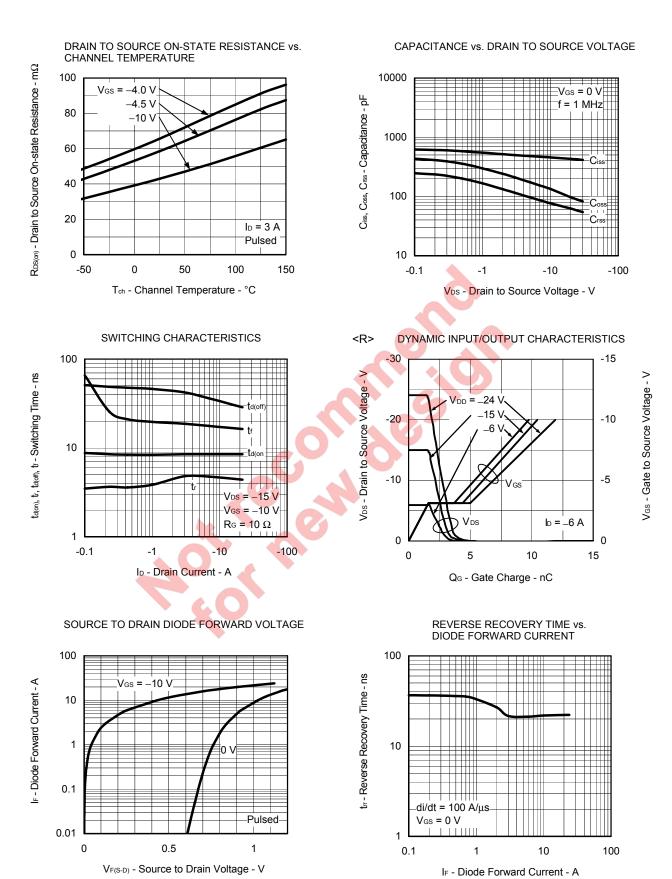
FORWARD TRANSFER CHARACTERISTICS











**μPA2790GR** 

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